GS1A THRU GS1M





SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIER

REVERSE VOLTAGE: 50 to 1000 VOLTS FORWARD CURRENT: 1.0 AMPERE

FEATURES

· For surface mounted applications

· Low profile package

· Built-in strain relief

· Easy pick and place

· Low forward voltage drop

· Plastic package has Underwriters Laboratory

Flammability Classification 94V-O

· High temperature soldering : 260°C /10 seconds at terminals

MECHANICAL DATA

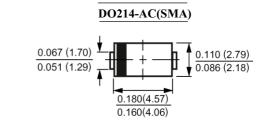
Case: Molded plastic, DO-214AC(SMA)

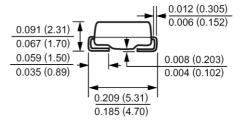
Terminals: Solder plated, solderable per MIL-STD-750,

method 2026 guaranteed

Polarity: Color band denotes cathode end Packaging: 12mm tape per EIA STD RS-481

Weight: 0.002 ounce, 0.064 gram





Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	GS1A	GS1B	GS1D	GS1G	GS1J	GS1K	GS1M	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T_L =75C	I _(AV)	1.0							Amp
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I_{FSM}	I _{FSM} 30							Amp
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage at 1.0A	V _F	1.1							Volts
Maximum Reverse Current at T _A =25C	τ,	5.0 100							μАтр
at Rated DC Blocking Voltage T _A =125C	I_R								
Typical Junction Capacitance (Note 1)	C _J	12							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	28							C/W
Maximum Reverse Recovery Time (Note 3)	T _{RR}	2.5							μS
Operating Junction Temperature Range	T_{J}	-55 to +150							С
Storage Temperature Range	Tstg	-55 to +150							C

NOTES:

- 1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2- Thermal resistance from junction to ambient mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas
- 3- Reverse Recovery Test Conditions I_F =.5A, I_R =1A, I_{RR} =.25A.





RATINGS AND CHARACTERISTIC CURVES

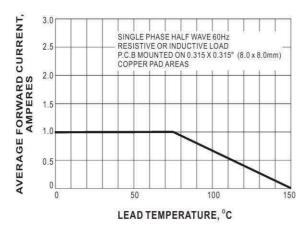
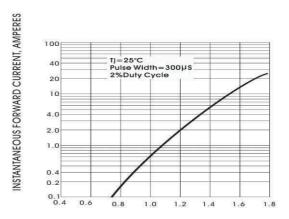


Fig.1-FORWARD CURRENT DERATING CURVE



INSTANTANEOUS FORWARD VOLTAGE, VOLTS
FIG. 2- TYPICAL INSTANTANEOUS FORWARD
CHARACTERISITCS PER ELEMENT

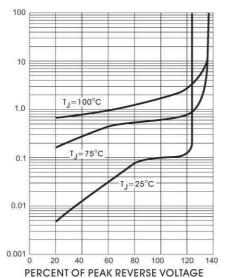


Fig. 3- TYPICAL REAK REVERSE CHARACTERISTICS

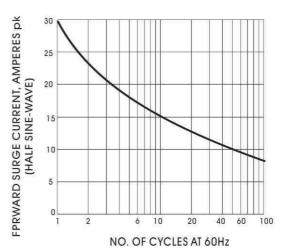


FIG. 4- MAXIMUM NON-REPETITEVE PEAK FORWARD SURGE CURRENT

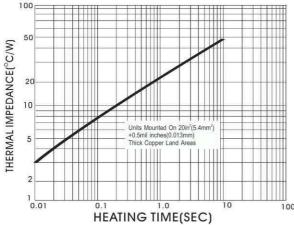


Fig. 5- TRANSIENT THERMAL IMPEDANCE

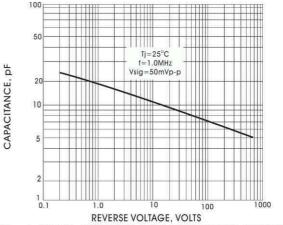


Fig. 6- TYPICL JUNCTION CAPACITANCE PER ELEMENT